

MM54HC257/MM74HC257 Quad 2-Channel TRI-STATE® Multiplexer

General Description

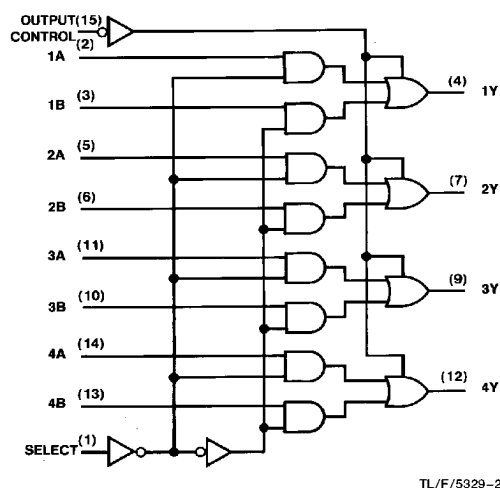
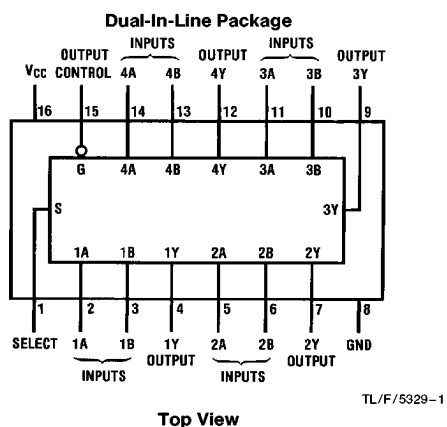
This QUAD 2-TO-1 line data selector/multiplexer utilizes advanced silicon-gate CMOS technology. Along with the high noise immunity and low power dissipation of standard CMOS integrated circuits, it possesses the ability to drive up to 15 LS-TTL loads. The large output drive capability coupled with the TRI-STATE feature make this device ideal for interfacing with bus lines in a bus organized system. When the OUTPUT CONTROL input line is taken high, the outputs of all four multiplexers are sent into a high impedance state. When the OUTPUT CONTROL line is low, the SELECT input chooses whether the A or B input is used.

The 54HC/74HC logic family is speed, function, and pin-out compatible with the standard 54LS/74LS logic family. All inputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

Features

- Typical propagation delay: 12 ns
- Wide power supply range: 2V–6V
- Low quiescent current: 80 μ A maximum (74HC Series)
- TRI-STATE outputs for connection to system buses.

Connection and Logic Diagrams



Truth Table

Output Control	Inputs			Output Y
	Select	A	B	
H	X	X	X	Z
L	L	L	X	L
L	L	H	X	H
L	H	X	L	L
L	H	X	H	H

H = high level, L = low level, X = irrelevant, Z = high impedance, (off)

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Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5 to +7.0V
DC Input Voltage (V_{IN})	−1.5 to V_{CC} + 1.5V
DC Output Voltage (V_{OUT})	−0.5 to V_{CC} + 0.5V
Clamp Diode Current (I_{IK} , I_{OK})	±20 mA
DC Output Current, per pin (I_{OUT})	±35 mA
DC V_{CC} or GND Current, per pin (I_{CC})	±70 mA
Storage Temperature Range (T_{STG})	−65°C to +150°C
Power Dissipation (P_D)	
(Note 3)	600 mW
S.O. Package only	500 mW
Lead Temp. (T_L) (Soldering 10 seconds)	260°C

Operating Conditions

	Min	Max	Units
Supply Voltage (V_{CC})	2	6	V
DC Input or Output Voltage (V_{IN} , V_{OUT})	0	V_{CC}	V
Operating Temp. Range (T_A)			
MM74HC	−40	+85	°C
MM54HC	−55	+125	°C
Input Rise or Fall Times (t_r , t_f)			
V_{CC} = 2.0V		1000	ns
V_{CC} = 4.5V		500	ns
V_{CC} = 6.0V		400	ns

DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V _{CC}	T _A = 25°C		74HC T _A = −40 to 85°C		54HC T _A = −55 to 125°C		Units
				Typ	Guaranteed Limits					
V _{IH}	Minimum High Level Input Voltage		2.0V		1.5	1.5	1.5	V		
			4.5V		3.15	3.15	3.15	V		
			6.0V		4.2	4.2	4.2	V		
V _{IL}	Maximum Low Level Input Voltage**		2.0V		0.5	0.5	0.5	V		
			4.5V		1.35	1.35	1.35	V		
			6.0V		1.8	1.8	1.8	V		
V _{OH}	Minimum High Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	2.0V	2.0	1.9	1.9	1.9	V		
			4.5V	4.5	4.4	4.4	4.4	V		
			6.0V	6.0	5.9	5.9	5.9	V		
		V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 6.0 mA I _{OUT} ≤ 7.8 mA	4.5V	4.2	3.98	3.84	3.7	V		
			6.0V	5.7	5.48	5.34	5.2	V		
V _{OL}	Maximum Low Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	2.0V	0	0.1	0.1	0.1	V		
			4.5V	0	0.1	0.1	0.1	V		
			6.0V	0	0.1	0.1	0.1	V		
		V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 6.0 mA I _{OUT} ≤ 7.8 mA	4.5V	0.2	0.26	0.33	0.4	V		
			6.0V	0.2	0.26	0.33	0.4	V		
I _{IN}	Maximum Input Current	V _{IN} = V _{CC} or GND	6.0V		± 0.1	± 1.0	± 1.0	μA		
I _{OZ}	Maximum TRI-STATE Output Leakage	V _{OUT} = V _{CC} or GND OC = V _{IH}	6.0V		± 0.5	± 5.0	± 10	μA		
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND I _{OUT} = 0 μA	6.0V		8.0	80	160	μA		

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: −12 mW/°C from 65°C to 85°C; ceramic "J" package: −12 mW/°C from 100°C to 125°C.

Note 4: For a power supply of 5V ±10% the worst case output voltages (V_{OH} , and V_{OL}) occur for HC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V_{IH} and V_{IL} occur at $V_{CC} = 5.5\text{V}$ and 4.5V respectively. (The V_{IH} value at 5.5V is 3.85V.) The worst case leakage current (I_{IN} , I_{CC} , and I_{OZ}) occur for CMOS at the higher voltage and so the 6.0V values should be used.

** V_{IL} limits are currently tested at 20% of V_{CC} . The above V_{IL} specification (30% of V_{CC}) will be implemented no later than Q1, CY'89.

AC Electrical Characteristics $V_{CC}=5V$, $T_A=25^{\circ}C$, $t_r=t_f=6\text{ ns}$

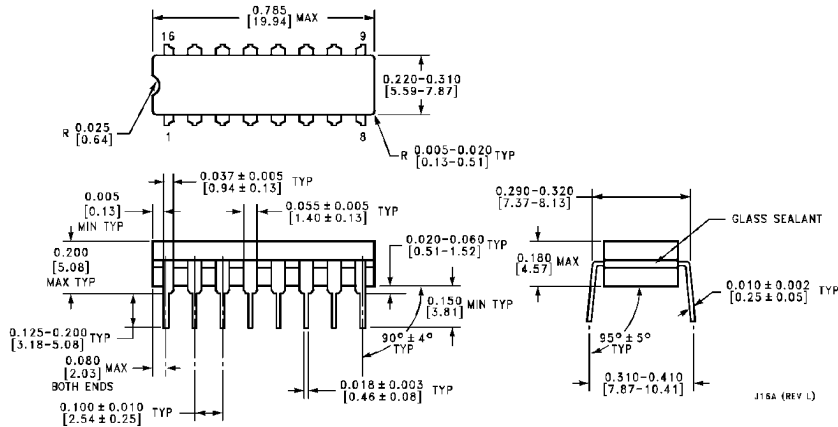
Symbol	Parameter	Conditions	Typ	Guaranteed Limit	Units
t_{PHL} , t_{PLH}	Maximum Propagation Delay, Select to any Y Output	$C_L = 45\text{ pF}$	12	18	ns
t_{PHL} , t_{PLH}	Maximum Propagation Delay, A or B to any Y Output	$C_L = 50\text{ pF}$	13	21	ns
t_{PZH} , t_{PZL}	Maximum Output Enable Time, any Y Output to a Logic Level	$R_L = 1\text{ k}\Omega$ $C_L = 45\text{ pF}$	17	28	ns
t_{PHZ} , t_{PLZ}	Maximum Output Disable Time, any Y Output to a High Impedance State	$R_L = 1\text{ k}\Omega$ $C_L = 5\text{ pF}$	15	25	ns

AC Electrical Characteristics $V_{CC}=2.0V$ to $6.0V$, $C_L=50\text{ pF}$, $t_r=t_f=6\text{ ns}$ (unless otherwise specified)

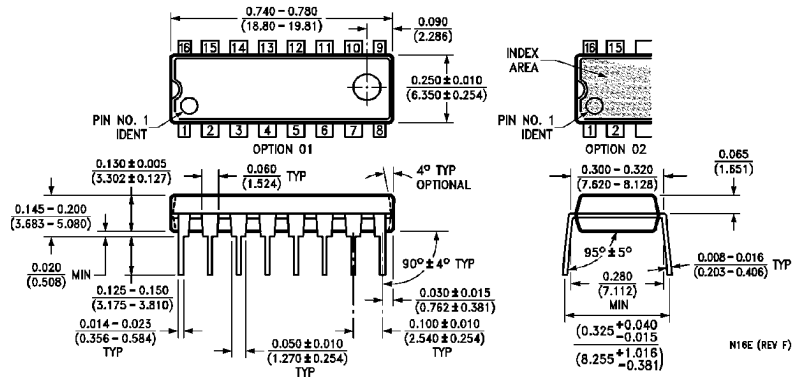
Symbol	Parameter	Conditions	V _{CC}	T _A = 25°C		74HC T _A = −40 to 85°C	54HC T _A = −55 to 125°C	Units
				Typ	Guaranteed Limits			
t _{PHL} , t _{PLH}	Maximum Propagation Delay, Select to any Y Output	C _L = 50 pF	2.0V	50	100	125	150	ns
		C _L = 150 pF	2.0V	70	150	189	224	ns
		C _L = 50 pF	4.5V	10	20	25	30	ns
		C _L = 150 pF	4.5V	15	30	38	45	ns
		C _L = 50 pF	6.0V	9	17	21	25	ns
		C _L = 150 pF	6.0V	13	26	32	38	ns
t _{PHL} , t _{PLH}	Maximum Propagation Delay, A or B to any Y Output	C _L = 50 pF	2.0V	50	100	125	150	ns
		C _L = 150 pF	2.0V	70	150	190	221	ns
		C _L = 50 pF	4.5V	10	20	29	30	ns
		C _L = 150 pF	4.5V	15	30	38	45	ns
		C _L = 50 pF	6.0V	10	17	21	25	ns
		C _L = 150 pF	6.0V	17	26	32	38	ns
t _{PZH} , t _{PZL}	Maximum Output Enable Time, any Y Output to a Logic Level	R _L = 1 kΩ						
		C _L = 50 pF	2.0V	75	150	189	224	ns
		C _L = 150 pF	2.0V	100	200	252	298	ns
		C _L = 50 pF	4.5V	15	30	38	45	ns
		C _L = 150 pF	4.5V	20	40	50	60	ns
		C _L = 50 pF	6.0V	13	26	32	38	ns
t _{PHZ} , t _{PLZ}	Maximum Output Disable Time, any Y Output to a High Impedance State	R _L = 1 kΩ	2.0V	75	150	189	224	ns
		C _L = 50 pF	4.5V	15	30	38	45	ns
			6.0V	13	26	32	38	ns
t _{THL} , t _{TLH}	Maximum Output Rise and Fall Time	C _L = 50 pF	2.0V		60	75	90	ns
			4.5V		12	15	18	ns
			6.0V		10	13	15	ns
C _{PD}	Power Dissipation Capacitance (Note 5)	(per mux) Enable Disabled		30 8				pF pF
C _{IN}	Maximum Input Capacitance			5	10	10	10	pF
C _{OUT}	Maximum Output Capacitance			10	20	20	20	pF

Note 5: C_{PD} determines the no load dynamic power consumption, $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$, and the no load dynamic current consumption, $I_S = C_{PD} V_{CC} f + I_{CC}$.

Physical Dimensions inches (millimeters)



Order Number MM54HC257J or MM74HC257J
NS Package J16A



Order Number MM74HC257N
NS Package N16E

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